L	Hits	Search Text	DB	Time stamp
-	2	(titanium near nitride) and (tin or (titanium	USPAT;	2004/02/21
		near nitride)).clm. and (active near	US-PGPUB;	21:02
		matrix).clm. and gate.clm. and	EPO; JPO;	
		electrode.clm. and (TFT or (thin near film	DERWENT;	
		near transistor)).clm. and (multilayer or	IBM_TDB	
		multilevel or multi-layer or multi-level).clm.		
-	35	(titanium near nitride) and (tin or (titanium	USPAT;	2004/02/21
		near nitride)).clm. and (nitrogen near	US-PGPUB;	21:03
		concentration).clm.	EPO; JPO;	
		,	DERWENT;	
			IBM_TDB	
_	7	(titanium near nitride) and ((tin or (titanium	USPAT;	2004/02/21
	•	near nitride)).clm. same (nitrogen near	US-PGPUB;	21:03
		concentration)).clm.	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
_	115	(titanium near nitride) and ((tin or (titanium	USPAT;	2004/02/21
•	119	near nitride)) same (nitrogen near	US-PGPUB;	21:03
		concentration))		21:03
		concentration))	EPO; JPO;	
			DERWENT;	
	445	(414	IBM_TDB	2004/02/04
-	115	(titanium near nitride) and (((tin or (titanium	USPAT;	2004/02/21
		near nitride)) same (nitrogen near	US-PGPUB;	21:03
		concentration)))	EPO; JPO;	
			DERWENT;	
	_		IBM_TDB	
-	3	(titanium near nitride) and (((tin or (titanium	USPAT;	2004/02/21
		near nitride)) same (nitrogen near	US-PGPUB;	21:04
		concentration))) and pixel	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	133	(titanium near nitride) and (((tin or (titanium	USPAT;	2004/02/21
		near nitride)) and (nitrogen near	US-PGPUB;	21:04
		concentration))) and pixel	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	78	(titanium near nitride) and (((tin or (titanium	USPAT;	2004/02/21
		near nitride)) and (nitrogen near	US-PGPUB;	21:04
		concentration))) and pixel.clm.	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	9	(titanium near nitride) and (((tin or (titanium	USPAT;	2004/02/21
		near nitride)).clm. and (nitrogen near	US-PGPUB;	21:04
		concentration))) and pixel.clm.	EPO; JPO;	
		***************************************	DERWENT;	
			IBM_TDB	

L	Hits	Search Text	DB	Time stamp
Number	7	(multilevel or multi-level or multilayer or	USPAT;	2004/02/21
-	•	multi-layer).clm. and (active near	US-PGPUB;	20:53
		matrix).clm. and (tin or (titanium near	EPO; JPO;	
		nitride)).clm.	DERWENT;	
		murue/j.c.m.	IBM_TDB	
	1	(multilevel or multi-level or multilayer or	USPAT:	2004/02/21
-	•	multi-layer).clm. and (active near	US-PGPUB;	20:53
		muti-layer).cim. and (active hear matrix).clm. and (tin or (titanium near	,	20.33
~		, , ,	EPO; JPO;	
		nitride)).clm. and (scan or scanning).clm.	DERWENT;	
			IBM_TDB	0004/00/04
-	36	(active near matrix).clm. and (tin or	USPAT;	2004/02/21
		(titanium near nitride)).clm. and (scan or	US-PGPUB;	20:53
		scanning).clm.	EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	19	(active near matrix).clm. and (tin or	USPAT;	2004/02/21
		(titanium near nitride)).clm. and (scan or	US-PGPUB;	20:54
		scanning).clm. and gate.clm. and	EPO; JPO;	
		electrode.clm. and (tft or (thin near film	DERWENT;	
		near transistor)).clm.	IBM_TDB	
-	19	(active near matrix).clm. and (tin or	USPAT;	2004/02/21
		(titanium near nitride)).clm. and ((scan or	US-PGPUB;	20:55
		scanning) near2 line).clm. and gate.clm.	EPO; JPO;	
		and electrode.clm. and (tft or (thin near film	DERWENT;	,
		near transistor)).clm.	IBM_TDB	
_	1	(active near matrix).clm. and (tin or	USPAT;	2004/02/21
	•	(titanium near nitride)).clm. and ((scan or	US-PGPUB;	20:55
		scanning) near2 line).clm. and gate.clm.	EPO; JPO;	
		and electrode.clm. and (tft or (thin near film	DERWENT;	
		near transistor)).clm. and (titanium near	IBM_TDB	
		,	IDM_IDD	
	_	nitride)	HEDAT.	2004/02/24
-	8	(active near matrix).clm. and (tin or	USPAT;	2004/02/21
		(titanium near nitride)).clm. and ((scan or	US-PGPUB;	20:55
		scanning) near2 line).clm. and gate.clm.	EPO; JPO;	
		and electrode.clm. and (tft or (thin near film	DERWENT;	
		near transistor)).clm. and (titanium)	IBM_TDB	

L	Hits	Search Text	DB	Time stamp
Number				
•	299	(active near matrix).ti,ab,clm. and (TFT or	USPAT;	2004/02/21
		(thin near film)).ti,ab,clm. and	US-PGPUB	20:43
		gate.ti,ab,clm. and ((scan or		
		scanning)).ti,ab,clm.		
-	240	(active near matrix).ti,ab,clm. and (TFT or	USPAT;	2004/02/21
		(thin near film)).ti,ab,clm. and	US-PGPUB	20:43
		gate.ti,ab,clm. and ((scan or		
		scanning)).ti,ab,clm. and		
		electrode.ti,ab,clm.		
-	4	(active near matrix).ti,ab,clm. and (TFT or	USPAT;	2004/02/21
		(thin near film)).ti,ab,clm. and	US-PGPUB	20:45
		gate.ti,ab,clm. and ((scan or		
		scanning)).ti,ab,clm. and		
		electrode.ti,ab,clm. and (nitrogen near		
		concentration).ti,ab,clm.		
-	7	(active near matrix).ti,ab,clm. and (TFT or	USPAT;	2004/02/21
		(thin near film)).ti,ab,clm. and	US-PGPUB	20:45
		gate.ti,ab,clm. and ((scan or		
		scanning)).ti,ab,clm. and		
		electrode.ti,ab,clm. and (nitrogen near		
		concentration)		